

Brian Fluegel

List of Publications by Year in descending order

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29

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1307594

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29

docs citations

29

times ranked

288

citing authors

#	ARTICLE	IF	CITATIONS
1	Triplet-pair spin signatures from macroscopically aligned heteroacenes in an oriented single crystal. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2022, 119, .	7.1	14
2	Charge transfer states and carrier generation in 1D organolead iodide semiconductors. <i>Journal of Materials Chemistry A</i> , 2021, 9, 14977-14990.	10.3	15
3	Direct observation of the quantum fluctuation driven amplitude mode in a microcavity polariton condensate. <i>Physical Review B</i> , 2021, 103, .	3.2	4
4	Carrier lifetime as a function of Se content for CdSe _x Te _{1-x} films grown on Al ₂ O ₃ and MgZnO. , 2021, ,.	3	
5	Crystallographically aligned 1.508 eV nitrogen pairs in ultra-dilute GaAs:N. <i>Japanese Journal of Applied Physics</i> , 2018, 57, 090302.	1.5	2
6	Spectrally resolved localized states in GaAs _{1-y} _x Bi _y . <i>Japanese Journal of Applied Physics</i> , 2017, 56, 035801.	1.5	9
7	Bismuth interstitial impurities and the optical properties of GaP _{1-y} _x Bi _y . <i>Japanese Journal of Applied Physics</i> , 2017, 56, 111201.		
8	Ferroelastic modulation and the Bloch formalism. <i>Science Advances</i> , 2017, 3, e1602754.	10.3	1
9	Ultra-low threshold polariton condensation. <i>Optics Letters</i> , 2017, 42, 1165.	3.3	5
10	Consequences of spatial antisymmetry on light. , 2016, ,.		0
11	Bismuth-induced Raman modes in GaP _{1-y} _x Bi _y . <i>Japanese Journal of Applied Physics</i> , 2016, 55, 108002.	1.5	7
12	Electronic Raman scattering as an ultra-sensitive probe of strain effects in semiconductors. <i>Nature Communications</i> , 2015, 6, 7136.	12.8	20
13	Mysterious absence of pair luminescence in gallium phosphide bismide. <i>Applied Physics Express</i> , 2015, 8, 061202.	2.4	9
14	Spectroscopic determination of the bandgap crossover composition in MBE-grown Al _x Ga _{1-x} As. <i>Japanese Journal of Applied Physics</i> , 2015, 54, 042402.	1.5	4
15	Magnetic field-induced direct-indirect crossover in Al _x Ga _{1-x} As. <i>Applied Physics Express</i> , 2014, 7, 111201.	2.4	1
16	Probing carrier lifetimes at dislocations in epitaxial CdTe. <i>Applied Physics Express</i> , 2014, 7, 065503.	2.4	5
17	Precise Determination of the Direct-Indirect Band Gap Energy Crossover Composition in Al _x Ga _{1-x} As. <i>Applied Physics Express</i> , 2013, 6, 071201.	2.4	7
18	Mechanism of asymmetric lineshape broadening in GaAs $\int_{\text{mml:math}}^{\text{mml:math}}$ $\text{xmlns:mml}=\text{"http://www.w3.org/1998/Math/MathML"}$ $\text{display}=\text{"inline"}$ $\langle \text{mml:msub} \rangle \langle \text{mml:mrow} \rangle \langle \text{mml:mn} \rangle 1 \langle / \text{mml:mn} \rangle \langle \text{mml:mo} \rangle \text{â''} \langle / \text{mml:mo} \rangle \langle \text{mml:mi} \rangle \times \langle / \text{mml:mi} \rangle \langle \text{mml:mrow} \rangle \langle / \text{mml:msub} \rangle \langle \text{mml:math} \rangle N \langle \text{mml:math} \rangle \text{xmlns:mml}=\text{"http://www.w3.org/1998/Math/MathML"}$ $\text{display}=\text{"inline"}$ $\langle \text{mml:msub} \rangle \langle \text{mml:mrow} \rangle \langle \text{mml:mi} \rangle x \langle / \text{mml:mi} \rangle \langle / \text{mml:msub} \rangle \langle / \text{mml:math} \rangle \text{Raman spectra. Physical Review B}$, 2012, 86, .		

#	ARTICLE	IF	CITATIONS
19	Eigenstate localization in an asymmetric coupled quantum well pair. <i>Superlattices and Microstructures</i> , 2012, 51, 834-841.	3.1	3
20	Investigation of effects of processing and impurities on the properties of CdTe using microscopic two-dimensional photoluminescence imaging technique. , 2009, , .		3
21	Ultrafast nonlinear gain dynamics in semiconductor nanocrystals. <i>Phase Transitions</i> , 1999, 68, 59-94.	1.3	6
22	Photoluminescence up-conversion inGaAs/Al _x Ga _{1-x} As heterostructures. <i>Physical Review B</i> , 1998, 58, R4254-R4257.	3.2	42
23	Quantum dots in the strong confinement regime: a model system for gain in quasi-zero-dimensional semiconductors. , 1996, , .		0
24	Observation of spectral hole sidebands in the gain region of an inverted semiconductor. , 1996, , .		0
25	Photoluminescence decay dynamics in an InGaN/AlGaN/GaN double-heterostructure blue-light-emitting diode. <i>Applied Physics Letters</i> , 1995, 67, 1515-1517.	3.3	39
26	Femtosecond nonlinear optics of semiconductor quantum wells. , 1992, , .		0
27	Femtosecond optical nonlinearities under resonant excitation of excitons in CdSe. <i>Journal of Crystal Growth</i> , 1992, 117, 768-772.	1.5	2
28	Femtosecond hole-burning and nonlinear dynamics of quantum-confined semiconductor-doped glasses. , 1990, , .		1
29	Design and Demonstration of Al _x In _{1-x} P Multiple Quantum Well Light-Emitting Diodes. <i>Journal Physics D: Applied Physics</i> , 0, , .	2.8	2